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APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY
THIRD SEMESTER B.TECH DEGREE EXAMINATION(R&S), DECEMBER 2019

Course Code: EC205

Course Name: ELECTRONIC CIRCUITS

Max. Marks: 100

Duration: 3 Hours

PART A

Answer any two full questions, each carries 15 marks.

Marks

- 1 a) Draw an RC differentiator circuit. Give the conditions for an RC circuit to behave as a differentiator. (4)
- b) Design an integrator for an input frequency of 1kHz. (3)
- c) A high pass RC circuit has a 3dB cut off frequency of 10Hz. Plot the output waveform of the circuit, if a 20Hz symmetric square wave with 2V peak to peak is applied to it. Mark the time and voltage levels accurately. (8)
- 2 a) Define stability factor for leakage current. Derive an equation for stability factor of emitter bias circuit. (4)
- b) For a fixed bias circuit with $R_B=300k\Omega$, $R_C=2k\Omega$, $\beta=50$, $V_{CC}=9V$, find the Q point and stability factor. (4)
- c) A silicon transistor with $\beta=50$ is used in a voltage divider bias circuit with $V_{BE}=0.6V$, $V_{CC}=22.5V$ and $R_C=5.6K$. It is desired to establish Q point at (8.2V, 2.3mA) and required stability factor is $S \leq 3$. Design the voltage divider circuit. (7)
- 3 a) Draw a common base amplifier circuit and show its small signal hybrid π model. (4)
- b) Prove that the mid band gain of an emitter follower circuit is approximately equal to unity. (5)
- b) For a RC coupled amplifier with bypass capacitor, the circuit components are $R_1=35.2 k\Omega$, $R_2=5.83 k\Omega$, $R_C=10k\Omega$, $R_E=1K$ and $R_S=0$. The transistor parameters are $V_{BE(ON)}=0.7V$, $V_A=100V$, and $\beta=100$. Determine the Q-point and small signal voltage gain [$V_{CC}=5V$]. (6)

PART B

Answer any two full questions, each carries 15 marks.

- 4 a) Explain the terms beta cut off frequency (f_β) and unity gain bandwidth (f_T) in relation with short circuit gain of a transistor. Derive an expression for f_β and f_T in terms of transistor parameters. (6)
- b) Determine the upper cut-off frequency of a common emitter amplifier (9)

configuration using hybrid π equivalent circuit.

- 5 a) What is a cascode amplifier? Draw the circuit diagram and derive an expression for mid band voltage gain of cascode amplifier. (9)
- b) An amplifier without feedback has a voltage gain of 50, input impedance $1\text{k}\Omega$ and output impedance $2.5\text{k}\Omega$. Obtain the input and output impedances of current-shunt negative feedback amplifier using the above amplifier with a feedback factor of 0.2. (6)
- 6 a) Draw the circuit diagram of a Wien bridge oscillator. Explain how Barkhausen criterion for oscillation is satisfied by the circuit and derive an expression for the frequency of oscillation. (8)
- b) Differentiate between synchronous and stagger tuned amplifiers. (3)
- c) Draw the circuit diagram of a Colpitts oscillator (4)

PART C

Answer any two full questions, each carries 20 marks.

- 7 a) Classify power amplifiers based on collector current waveforms and conduction angle. (5)
- b) Draw the circuit diagram of class A series fed power amplifier and prove that the conversion efficiency is 50% by using transformer coupling. (10)
- c) What is cross over distortion in class B power amplifier? How is it avoided? (5)
- 8 a) Draw the circuit diagram of bootstrap sweep circuit. (4)
- b) Explain the working of an astable multivibrator with necessary base and collector waveforms. (9)
- c) Derive an expression for the free running frequency of astable multivibrator. (7)
- 9 a) With a neat circuit diagram explain the working of a transistor based shunt voltage regulator. (9)
- b) How is short circuit protection provided in series voltage regulator. (7)
- c) Analyze a common source amplifier with source resistance bypassed and derive expressions for input impedance, output impedance and voltage gain using small signal equivalent circuit.. (4)
